

SEMICONDUCTOR TECHNICAL DATA

KAB3405T

BICD LINEAR INTEGRATED CIRCUIT

Step Up Type DC/DC Converter for White LED

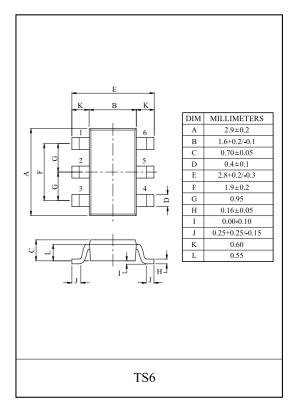
KAB3405T is a high efficient Step-Up Type DC/DC Converter specially designed for constant current drive of White LED. This IC can drive 2-10 white LEDs connected series using a Li-ion Battery. This IC contains N-ch MOS-FET Transistor for Coil-Switching, and LED Current (I_F) is set with an external resistor.

Features

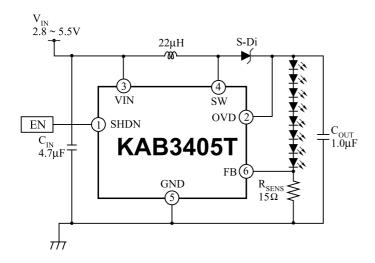
- · Variable LED Current I_F is set with a external resistor
- : 20 mA (Typ.) @ $R_{SENS} = 15 \Omega$
- · High Efficiency
- · Output Over Voltage Shutdown
- · Built in output over voltage protect circuit.
- · Switching Frequency: 1.0 MHz (Typ.)

Applications

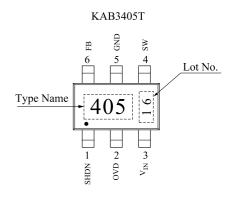
- · Back light white LEDs in LCD of PDA, Cellular Phone
- · Handy Terminal Equipment.



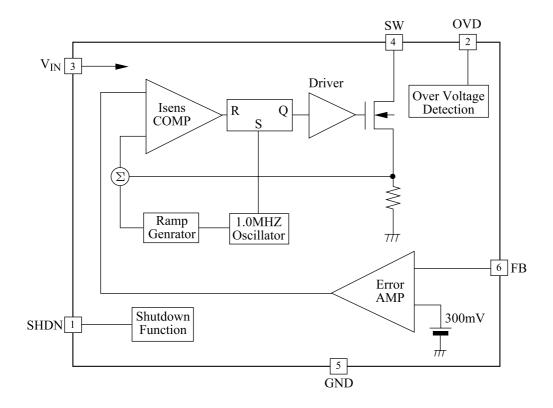
Basic Application Circuit



Marking



Block Diagram



Pin Function

Pin No.	Symbol	Function Description
1	SHDN	Voltage-Input Terminal for IC-Enable / Disable.
2	OVD	Over Voltage Detection Terminal. IC Switching Operation is disabled with detection over voltage. If the voltage returns
	0,12	to detection level or less, Operation is enabled again.
3	V_{IN}	Supply Voltage Input Terminal. (2.8V to 5.5V)
4	SW	Switch Terminal for DC/DC Converter. Nch MOSFET Built-In.
5	GND	Ground Terminal.
6	FB	LED I _F Setting Resister Connecting Terminal.

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MAXIMUM RATINGS (Ta = 25°C if without notice)

Characteristics	Symbol	Ratings	Unit	
Power Supply Voltage	V _{IN}	-0.3 to +6.0	V	
Input Voltage	V _{IN(SHDN)}	$-0.3 \text{ to } +V_{\text{IN}} + 0.3$	V	
Switching Terminal Voltage	V _{O (SW)}	-0.3 to 40	V	
Switching Terminal Current	I _{O (SW)}	1500	mA	
Power Dissipation	P_{D}	0.41 (Device)	W	
1 Ower Dissipation	1 D	0.47(on PCB)Caution 2		
Thermal Resistance	P	300(Device)	°C/W	
Thermal Resistance	R _{th(j-a)}	260(on PCB)		
Operation Temperature Range	T _{opr}	-40 to +85	$^{\circ}$ C	
Storage Temperature Range	T _{stg}	-55 to +150	$^{\circ}$ C	
Maximum Junction Temperature	T _j	150	$^{\circ}$ C	

Caution 2: Power Dissipation must be calculated with subtraction of 3.8 mW/° C from Maximum Rating with every 1 °C if Topr is upper 25 °C. (on PCB)

ELECTRICAL CHARACTERISTICS (Ta = 25 $^{\circ}$ C, V_{IN} =2.8V to 5.5V if without notice)

Characteristics	Symbol	Test Condition	Min	Тур	Max	Unit
Input Voltage Range	V _{IN}	-	2.8	-	5.5	V
Operating Consumption Current	I _{N(ON)}	V_{IN} =3.6V, R_{SENS} =15 Ω	-	0.6	0.9	mA
Quiescent Consumption Current	I _{N(Off)}	$V_{IN}=3.6V, V_{SHDN}=0V$	-	0.5	1.0	μA
SHDNTerminal 'H' Level Input Voltage	V _{SHDNH}	-	1.3	-	V _{IN}	V
SHDN Terminal 'L' Level Input Voltage	V _{SHDNL}	-	0	-	0.4	V
SHDN Terminal Current	I _{SHDN}	V _{IN} =3.6V,V _{SHDN} =3.6V or 0V	-	0	1.0	μА
Integrated MOS-Tr Switching requency	f_{OSC}	V _{IN} =3.6V,V _{SHDN} =3.6V	0.77	1.0	1.43	MHz
Switching Terminal Leak Current	I _{OZ(SW)}	-	-	0.5	1	μА
FB Terminal Feedback Voltage (V _{FB})	V _{FB}	V_{IN} =3.6V, R_{SENS} =15 Ω , Ta =25 $^{\circ}$ C, L=22 μ H	285	300	315	mV
rb reminar recuoack voltage (v _{FB})		V_{IN} =4.2V, R_{SENS} =15 Ω , Ta =25 $^{\circ}$ C, L=22 μ H	285	300	315	mV
FB Terminal Line Regulation	V_{FB}	V_{IN} =3.6V center V_{IN} =3.0 to 5.0V	-5	-	5	%
FB Terminal Current	I_{FB}	$V_{IN}=3.6V, V_{SHDN}=3.6V, V_{FB}=300mV$	-	0.02	-	μА
OVD terminal Voltage	V _{OVD}	-	35	38	39.5	V
OVD Terminal Leakage Current	I _{OVD}	V _{OVD} =30V	-	0.5	1	μА

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Protection in LED opened condition

The operation with OVD terminal is available for the protection in case LED Circuit opened.

When the voltage of OVD terminal is over 38V (typ.), Nch MOS switching operation is disabled in the IC. When the voltage of OVD terminal drops below 38V (typ.), Nch MOS switching operation becomes available again.

If load of LED is detached, Nch MOS switching operation is disabled with detection of boost circuit voltage and the IC is protected from unexpected over voltage.

Setting of external Capacitor

recommended values are

$$C_{IN} = Over 2.2 (\mu F), C_{OUT} = Over 1.0 (\mu F)$$

The recommended values of the capacitors depend on the control of brightness. For details, please see the item "Control of brightness" from the next page.)

These recommended values reduce fluctuation of input current to up accuracy of brightness.

<Please see after page-6>

The capacitor value must be considered for gain enough accuracy of brightness with reduction of noise from Input current changing.

Setting of External Inductor Size

Please select the inductor size with referring this table corresponding to each number of LEDs.

Recommendation for the case that LED current I_F = 20 mA

LEDs	Inductor Size	Note
2 - 5	10μΗ	LED current $I_F = 20 \text{ mA}$
Over 6	22μΗ	LLD current IF - 20 IIIA

Setting of I_F

Resistance connects between R_{SENS} pin and GND.

The average current is set by this R_{SENS} value and average current are obtained by the following equation.

$$I_{F}[mA] = \frac{300[mV]}{R_{SENS}[\Omega]}$$

Current Value error is within $\pm 5\%$.

Current Dimming Control

Recommended Brightness Control Circuits are 3 types.

1) Input analog voltage to FB terminal

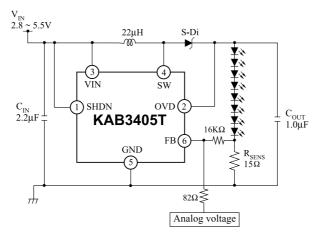
I_F can be adjusted with Analog voltage input to FB terminal.

This method is without repeating IC ON/OFF, and no consider holding rash current.

[Notice]

 \cdot LED current value goes ever 100% of current set with R_{SENS} , if the input voltage is between 0 V to 300 mV(typ)

<< Recommended application>>



2) Input PWM signal with filtering to FB terminal

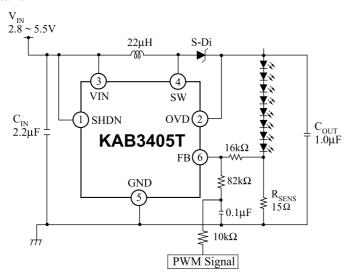
 I_F can be adjusted with filtering PWM signal using RC filter indicated in recommended circuit, because the PWM signal can be regard as analog voltage after filtering.

This method is without repeating IC ON/OFF, and no need to consider holding rash current.

[Notice]

· LED current value goes over 100% of the current set with R_{SENS} , if the input voltage after filtering is between 0 V to 300 mV (typ).

<< Recommended application>>



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3) Input Logic signal

I_F can be adjusted with Logic signal input as indicated in recommended circuit.

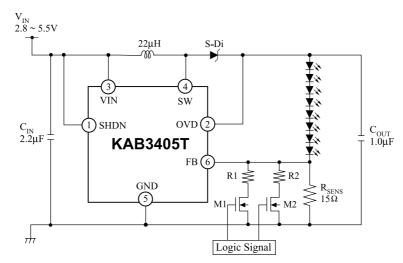
The resistor connected the ON-state Nch MOS Drain and R_{SENS} determines I_{F} .

Average of setting current Io (mA) is next, approximately.

 I_F =(300 [mV]/Sum of resistor value [Ω])

$$I_F [mA] = \frac{300[mV]}{\text{Sum of resistor v alue } [\Omega]}$$

<< Recommended application>>



M1	M2	LED Current	
OFF	OFF	$\frac{300 [\text{mV}]}{R_{\text{SENS}}[\Omega]}$	
ON	OFF	$300[\text{mV}] imes \frac{R_{\text{SENS}}[\Omega] R1[\Omega]}{R_{\text{SENS}}[\Omega] + R1[\Omega]}$	
OFF	ON	$300[\text{mV}] \times \frac{R_{\text{SENS}}[\Omega] R2[\Omega]}{R_{\text{SENS}}[\Omega] + R2[\Omega]}$	
ON	ON	$300 [\text{mV}] \times \frac{R_{SENS}[\Omega] \ R1[\Omega] \ R2[\Omega]}{R_{SENS}[\Omega] \ R1[\Omega] + R_{SENS}[\Omega] \ R2[\Omega] + R1[\Omega] \ R2[\Omega]}$	